

 $\frac{1}{2}$ Now

[Reference](http://www.ti.com.cn/tool/PMP5547?dcmp=dsproject&hqs=rd) Design

ZHCSI26C –AUGUST 2010–REVISED APRIL 2018

TPS54320 4.5V 至 **17V** 输入、**3A** 同步降压 **SWIFT™** 转换器

1 特性

¹• 集成 57mΩ/50mΩ MOSFET

INSTRUMENTS

- 分离电源轨:PVIN 上的电压为 1.6V 至 17V
- 200kHz 至 1.2MHz 开关频率
- 与外部时钟同步

TEXAS

- 0.8V 基准电压, 精度为 ±1%
- 低至 2µA 的关断静态电流
- 断续模式过流保护
- 单调启动至预偏置输出
- **-40℃ 至 150℃ 工作结温范围**
- 与 TPS54620 之间实现引脚对引脚兼容
- 可调慢速启动/电源排序
- 提供电源正常输出以进行欠压和过压监控
- 可调节输入欠压锁定 (UVLO)
- 由 SwitcherPro™软件工具支持
- 如需 SWIFT ™文档和 SwitcherPro, 请访问 www.ti.com.cn/swift
- 使用 TPS54320 并借助 [WEBENCH](https://webench.ti.com/wb5/WBTablet/PartDesigner/quickview.jsp?base_pn=TPS54320&origin=ODS&litsection=features)[®] 电源设计器 创建定制设计方案

2 应用

- 宽带、网络和通信基础设施
- 自动化测试和医疗设备
- DSP 和 FPGA 负载点 应用 (采用 12V 总线)

简化原理图

3 说明

TPS54320 是一款全功能 17V、3A 同步降压转换器, 此器件具有高效率并集成了高侧和低侧 MOSFET, 因 此非常适合小型设计。此器件通过电流模式控制来减少 组件数量,并通过选择高开关频率来缩小电感器封装尺 寸,从而进一步节省空间。

Support & [Community](http://www.ti.com.cn/product/cn/TPS54320?dcmp=dsproject&hqs=support&#community)

 22

输出电压启动斜坡由 SS/TR 引脚控制,可实现独立电 源运行,或者跟踪状态下的运行。此外,正确配置启用 与开漏电源正常引脚也可实现电源排序。

高侧 FET 上的逐周期电流限制可在过载情况下保护器 件,并可通过防止电流失控的低侧源电流限制实现增 强。当过流持续时间超出预设时间时,将触发断续模式 保护。裸片温度超过热关断温度时,热关断功能会禁用 此部件。TPS54320 采用 14 引脚 3.5mm × 3.5mm VQFN 热增强型封装。

器件信息**[\(1\)](#page-0-0)**

(1) 如需了解所有可用封装,请参阅数据表末尾的可订购产品附 录。

效率与负载电流间的关系

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, **44 intellectual property matters and other important disclaimers. PRODUCTION DATA.**

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1 特性.. [1](#page-0-1) **2** 应用.. [1](#page-0-0)

5 Pin Configuration and Functions......................... [3](#page-2-0) **6 Specifications**... [4](#page-3-0) 6.1 Absolute Maximum Ratings [4](#page-3-1) 6.2 ESD Ratings.. [4](#page-3-2) 6.3 Recommended Operating Conditions....................... [4](#page-3-3) 6.4 Thermal Information.. [5](#page-4-0) 6.5 Electrical Characteristics... [5](#page-4-1) 6.6 Typical Characteristics .. [7](#page-6-0) **7 Detailed Description** .. [10](#page-9-0) 7.1 Overview ... [10](#page-9-1) 7.2 Functional Block Diagram [11](#page-10-0) 7.3 Feature Description... [11](#page-10-1)

2

注:之前版本的页码可能与当前版本有所不同。

Changes from Revision B (November 2014) to Revision C Page

Changes from Revision A (September 2010) to Revision B Page

EXAS **STRUMENTS**

7.4 Device Functional Modes.. [21](#page-20-0) **8 Application and Implementation** [23](#page-22-0) 8.1 Application Information.. [23](#page-22-1) 8.2 Typical Application ... [23](#page-22-2) **9 Power Supply Recommendations**...................... [33](#page-32-0) **10 Layout**... [33](#page-32-1) 10.1 Layout Guidelines ... [33](#page-32-2) 10.2 Layout Example .. [34](#page-33-0) **11** 器件和文档支持 ... [35](#page-34-0) 11.1 器件支持.. [35](#page-34-1) 11.2 文档支持.. [35](#page-34-2) 11.3 商标... [35](#page-34-3) 11.4 静电放电警告... [35](#page-34-4) 11.5 术语表 ... [35](#page-34-5) **12** 机械、封装和可订购信息....................................... [35](#page-34-6)

5 Pin Configuration and Functions

Pin Functions

6 Specifications

6.1 Absolute Maximum Ratings

over operating temperature range (unless otherwise noted)⁽¹⁾

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

6.4 Thermal Information

(1) For more information about traditional and new thermal metrics, see the *[Semiconductor](http://www.ti.com/cn/lit/pdf/SPRA953) and IC Package Thermal Metrics* application report.

(2) Power rating at a specific ambient temperature T_A should be determined with a junction temperature of 150°C. This is the point where distortion starts to substantially increase. Thermal management of the PCB should strive to keep the junction temperature at or below 150°C for best performance and long-term reliability. See power dissipation estimate in application section of this data sheet for more information.

(3) Test board conditions:

(a) 2.5 inches × 2.5 inches, 4 layers, thickness: 0.062 inch

(b) 2-oz. copper traces located on the top of the PCB

(c) 2-oz. copper ground planes on the 2 internal layers and bottom layer

(d) 40.010-inch thermal vias located under the device package

6.5 Electrical Characteristics

 T_J = -40°C to 150°C, VIN = 4.5 to 17 V, PVIN = 1.6 to 17 V (unless otherwise noted)

(1) Measured at pins

ISTRUMENTS

TEXAS

Electrical Characteristics (continued)

 T_J = -40°C to 150°C, VIN = 4.5 to 17 V, PVIN = 1.6 to 17 V (unless otherwise noted)

6.6 Typical Characteristics

[TPS54320](http://www.ti.com.cn/product/cn/tps54320?qgpn=tps54320) ZHCSI26C –AUGUST 2010–REVISED APRIL 2018 **www.ti.com.cn**

Typical Characteristics (continued)

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Typical Characteristics (continued)

7 Detailed Description

7.1 Overview

The device is a 17-V, 3-A, synchronous step-down (buck) converter with two integrated N-channel MOSFETs. To improve performance during line and load transients the device implements a constant frequency, peak current mode control which also simplifies external frequency compensation. The wide switching frequency of 200 to 1200 kHz allows for efficiency and size optimization when selecting the output filter components. The switching frequency is adjusted using a resistor to ground on the RT/CLK pin. The device also has an internal phase lock loop (PLL) controlled by the RT/CLK pin that can be used to synchronize the switching cycle to the falling edge of an external system clock.

The device has been designed for safe monotonic start-up into prebiased loads. The default start up is when VIN is typically 4.0 V. The EN pin has an internal pullup current source that can be used to adjust the input voltage UVLO with two external resistors. In addition, the EN pin can be left floating for the device to automatically start with the internal pullup current. The total operating current for the device is approximately 600 μA when not switching and under no load. When the device is disabled, the supply current is typically less than 2 μA.

The integrated MOSFETs allow for high-efficiency power supply designs with continuous output currents up to 3 A. The MOSFETs have been sized to optimize efficiency for lower duty cycle applications.

The device reduces the external component count by integrating the boot recharge circuit. The bias voltage for the integrated high-side MOSFET is supplied by a capacitor between the BOOT and PH pins. The boot capacitor voltage is monitored by a BOOT to PH UVLO (BOOT-PH UVLO) circuit allowing PH pin to be pulled low to recharge the boot capacitor. The device can operate at 100% duty cycle, as long as the boot capacitor voltage is higher than the preset BOOT-PH UVLO threshold, which is typically 2.1 V. The output voltage can be stepped down to as low as the 0.8-V voltage reference (Vref).

The device has a power good comparator (PWRGD) with hysteresis which monitors the output voltage through the VSENSE pin. The PWRGD pin is an open drain MOSFET which is pulled low when the VSENSE pin voltage is less than 91% or greater than 109% of the reference voltage Vref and floats high when the VSENSE pin voltage is 94% to 106% of the Vref.

The SS/TR (slow start/tracking) pin is used to minimize inrush currents or provide power supply sequencing during power up. A small value capacitor or resistor divider should be attached to the pin for slow-start or critical power supply sequencing requirements.

The device is protected from output overvoltage, overload, and thermal fault conditions. The device minimizes excessive output overvoltage transients by taking advantage of the overvoltage circuit power good comparator. When the overvoltage comparator is activated, the high-side MOSFET is turned off and prevented from turning on until the VSENSE pin voltage is lower than 106% of the Vref. The device implements both high-side MOSFET overload protection and bidirectional low-side MOSFET overload protections which help control the inductor current and avoid current runaway. If the overcurrent condition has lasted for more than the hiccup wait time, the device will shut down and restart after the hiccup time. The device also shuts down if the junction temperature is higher than thermal shutdown trip point. The device is restarted under control of the slow-start circuit automatically when the junction temperature drops 10°C typically below the thermal shutdown trip point.

7.2 Functional Block Diagram

7.3 Feature Description

7.3.1 Fixed Frequency PWM Control

The device uses adjustable, fixed frequency, peak current mode control. The output voltage is compared through external resistors on the VSENSE pin to an internal voltage reference by an error amplifier which drives the COMP pin. An internal oscillator initiates the turn on of the high-side power switch. The error amplifier output is converted into a current reference which is compared to the high-side power switch current. When the power switch current reaches the current reference generated by the COMP voltage level, the high-side power switch is turned off and the low-side power switch is turned on.

7.3.2 Continuous Current Mode Operation (CCM)

As a synchronous buck converter, the device normally works in CCM under all load conditions.

7.3.3 VIN and Power VIN Pins (VIN and PVIN)

The device allows for a variety of applications by using the VIN and PVIN pins together or separately. The VIN pin voltage supplies the internal control circuits of the device. The PVIN pin voltage provides the input voltage to the power converter system.

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Feature Description (continued)

If tied together, the input voltage for VIN and PVIN can range from 4.5 to 17 V. If using the VIN separately from PVIN, the VIN pin must be between 4.5 and 17 V, and the PVIN pin can range from as low as 1.6 to 17 V. A voltage divider connected to the EN pin can adjust either input voltage UVLO appropriately. Adjusting the input voltage UVLO on the PVIN pin helps to provide consistent power up behavior.

7.3.4 Voltage Reference

The voltage reference system produces a precise voltage reference by scaling the output of a temperature stable bandgap circuit.

7.3.5 Adjusting the Output Voltage

The output voltage is set with a resistor divider from the output (VOUT) to the VSENSE pin. TI recommends to use 1% tolerance or better divider resistors. Referring to the application schematic of [Figure](#page-22-3) 34, start with a 10 kΩ resistor for R9 and use [Equation](#page-11-0) 1 to calculate R8. To improve efficiency at light loads, consider using larger value resistors. If the values are too high, the regulator is more susceptible to noise and voltage errors from the VSENSE input current are noticeable.

$$
R8 = \frac{Vout - Vref}{Vref}R9
$$

where

• $Vref = 0.8 V$ (1)

The minimum output voltage and maximum output voltage can be limited by the minimum on time of the highside MOSFET and bootstrap voltage (BOOT-PH voltage) respectively. See *[Minimum](#page-26-0) Output Voltage* and *Bootstrap Voltage (BOOT) and Low Dropout [Operation](#page-13-1)* for more information.

7.3.6 Safe Start-up into Prebiased Outputs

The device is designed to prevent the low-side MOSFET from discharging a prebiased output. During monotonic prebiased start-up, the low-side MOSFET is not allowed to turn on until the SS/TR pin voltage is higher than the VSENSE pin voltage.

7.3.7 Error Amplifier

The device uses a transconductance error amplifier. The error amplifier compares the VSENSE pin voltage to the lower of the SS/TR pin voltage or the internal 0.8-V voltage reference. The transconductance of the error amplifier is 1300 μA/V during normal operation. The frequency compensation network is connected between the COMP pin and ground.

7.3.8 Slope Compensation

The device adds a compensating ramp to the switch current signal. This slope compensation prevents subharmonic oscillations. The available peak inductor current remains constant over the full duty cycle range.

7.3.9 Enable and Adjusting UVLO

The EN pin provides an electrical on/off control of the device. After the EN pin voltage exceeds the threshold voltage, the device starts operation. If the EN pin voltage is pulled below the threshold voltage, the regulator stops switching and enters a low Iq state.

The EN pin has an internal pullup current source, allowing the user to float the EN pin for enabling the device. If an application requires controlling the EN pin, use an open-drain or open collector output logic to interface with the pin.

The device implements internal UVLO circuitry on the VIN pin. The device is disabled when the VIN pin voltage falls below the internal VIN UVLO threshold. The internal VIN UVLO threshold has a hysteresis of 150 mV.

If an application requires either a higher UVLO threshold on the VIN pin or a secondary UVLO on the PVIN pin, in split rail applications, then the EN pin can be configured as shown in [Figure](#page-12-3) 17, Figure 18, or Figure 19. When using the external UVLO function, TI recommends to set the hysteresis to be >500 mV.

The EN pin has a small pullup current Ip which sets the default state of the pin to enable when no external components are connected. The pullup current is also used to control the voltage hysteresis for the UVLO function because it increases by I_h after the EN pin crosses the enable threshold. The UVLO thresholds can be calculated using [Equation](#page-12-4) 2 and [Equation](#page-12-0) 3.

Figure 17. Adjustable VIN UVLO

Figure 18. Adjustable PVIN UVLO, VIN ≥ 4.5 V

Figure 19. Adjustable VIN and PVIN UVLO

(2)

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Feature Description (continued)

where

- $I_h = 2.25 \mu A$
- $I_p = 1.15 \mu A$
- \bullet V_{ENRISING} = 1.21 V
- $V_{ENFALLING} = 1.17 \text{ V}$ (3)

7.3.10 Slow Start (SS/TR)

The device uses the lower voltage of the internal voltage reference or the SS/TR pin voltage as the reference voltage and regulates the output accordingly. A capacitor on the SS/TR pin to ground implements a slow-start time. The device has an internal pullup current source of 2.3 μA that charges the external slow-start capacitor. [Equation](#page-13-2) 4 shows the calculations for the slow-start time (t_{SS} , 10% to 90%) and slow-start capacitor (Css). The voltage reference (Vref) is 0.8 V and the slow-start charge current (Iss) is 2.3 μA.

$$
t_{SS} \text{ (ms)} = \frac{\text{Css (nF)} \times \text{Vref (V)}}{\text{lss (µA)}} \tag{4}
$$

When the input UVLO is triggered, the EN pin is pulled below 1.21 V or a thermal shutdown event occurs; the device stops switching and enters low current operation. At the subsequent power-up, when the shutdown condition is removed, the device does not start switching until it has discharged its SS/TR pin to ground ensuring proper soft-start behavior.

7.3.11 Power Good (PWRGD)

The PWRGD pin is an open-drain output. When the VSENSE pin is between 94% and 106% of the internal voltage reference, the PWRGD pin pull-down is deasserted and the pin floats. TI recommends to use a pullup resistor between the values of 10 and 100 kΩ to a voltage source that is 5.5 V or less. The PWRGD is in a defined state when the VIN input voltage is >1 V, but with reduced current sinking capability. The PWRGD achieves full current sinking capability when the VIN input voltage is above 4.5 V.

The PWRGD pin is pulled low when VSENSE is lower than 91% or greater than 109% of the nominal internal reference voltage. Also, the PWRGD is pulled low, if the input UVLO or thermal shutdown are asserted, the EN pin is pulled low, or the SS/TR pin is below 1.2 V typically.

7.3.12 Bootstrap Voltage (BOOT) and Low Dropout Operation

The device has an integrated boot regulator, and requires a small ceramic capacitor between the BOOT and PH pins to provide the gate drive voltage for the high-side MOSFET. The boot capacitor is charged when the BOOT pin voltage is less than VIN and BOOT-PH voltage is below regulation. The value of this ceramic capacitor should be 0.1 μF. TI recommends a ceramic capacitor with an X7R or X5R grade dielectric with a voltage rating of 10 V or higher because of the stable characteristics over temperature and voltage.

To improve dropout, the device is designed to operate at 100% duty cycle as long as the BOOT to PH pin voltage is greater than the BOOT-PH UVLO threshold which is typically 2.1 V. When the voltage between BOOT and PH drops below the BOOT-PH UVLO threshold, the high-side MOSFET is turned off and the low-side MOSFET is turned on allowing the boot capacitor to be recharged. In applications with split input voltage rails, 100% duty cycle operation can be achieved as long as $(VIN - PVIN) > 4 V$.

Never use a boot resistor in series with the boot capacitor on the TPS54320.

7.3.13 Sequencing (SS/TR)

14

Many of the common power-supply sequencing methods can be implemented using the SS/TR, EN, and PWRGD pins.

[Figure](#page-14-0) 20 shows the sequential method using two TPS54320 devices. The power good of the first device is coupled to the EN pin of the second device which enables the second power supply once the primary supply reaches regulation. [Figure](#page-14-0) 21 shows the results of [Figure](#page-14-0) 20.

Figure 20. Sequential Start-Up Sequence

Figure 21. Sequential Start-Up Using EN and PWRGD

[Figure](#page-14-1) 22 shows the method implementing ratiometric sequencing by connecting the SS/TR pins of two devices together. The regulator outputs ramp up and reach regulation at the same time. When calculating the slow-start time, the pullup current source must be doubled in [Equation](#page-13-2) 4. [Figure](#page-14-1) 23 shows the results of [Figure](#page-14-1) 22.

Figure 22. Ratiometric Start-Up Sequence

Ratiometric and simultaneous power-supply sequencing can be implemented by connecting the resistor network of R1 and R2 shown in [Figure](#page-15-0) 24 to the output of the power supply that needs to be tracked or another voltage reference source. Using [Equation](#page-15-1) 5 and [Equation](#page-15-2) 6, the tracking resistors can be calculated to initiate the Vout2 slightly before, after, or at the same time as Vout1. [Equation](#page-15-3) 7 is the voltage difference between Vout1 and Vout2.

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To design a ratiometric start-up in which the Vout2 voltage is slightly greater than the Vout1 voltage when Vout2 reaches regulation, use a negative number in [Equation](#page-15-1) 5 and [Equation](#page-15-2) 6 for ΔV. [Equation](#page-15-3) 7 results in a positive number for applications where the Vout2 is slightly lower than Vout1 when Vout2 regulation is achieved. [Figure](#page-16-2) 25 and Figure 26 show the results for positive ΔV and negative ΔV respectively.

The ΔV variable is 0 V for simultaneous sequencing. To minimize the effect of the inherent SS/TR to VSENSE offset (Vssoffset, 29 mV) in the slow-start circuit and the offset created by the pullup current source (Iss, 2.3 μA) and tracking resistors, the Vssoffset and Iss are included as variables in the equations. [Figure](#page-16-2) 27 shows the result when $\Delta V = 0$ V.

To ensure proper operation of the device, the calculated R1 value from [Equation](#page-15-1) 5 must be greater than the value calculated in [Equation](#page-15-4) 8.

$$
\Delta V = Vout1 - Vout2 \tag{7}
$$
\n
$$
R1 > 2800 \times Vout1 - 180 \times \Delta V \tag{8}
$$

$$
R1 > 2800 \times Vout1 - 180 \times \Delta V \tag{8}
$$

Figure 24. Ratiometric and Simultaneous Start-Up Sequence

7.3.14 Output Overvoltage Protection (OVP)

The device incorporates an output OVP circuit to minimize output voltage overshoot. For example, when the power supply output is overloaded, the error amplifier compares the actual output voltage to the internal reference voltage. If the VSENSE pin voltage is lower than the internal reference voltage for a considerable time, the output of the error amplifier demands maximum output current. After the condition is removed, the regulator output rises and the error amplifier output transitions to the steady state voltage. In some applications with small output capacitance, the power supply output voltage can respond faster than the error amplifier. This leads to the possibility of an output overshoot. The OVP feature minimizes the overshoot by comparing the VSENSE pin voltage to the OVP threshold. If the VSENSE pin voltage is greater than the OVP threshold, the high-side MOSFET is turned off to minimize output overshoot. The OVP threshold is the same as the VSENSE rising (fault) threshold of 109%. When the VSENSE voltage drops lower than the VSENSE falling (good) threshold of 106%, the high-side MOSFET is allowed to turn on at the next clock cycle.

7.3.15 Overcurrent Protection

The device is protected from overcurrent conditions by cycle-by-cycle current limiting on both the high-side MOSFET and low-side MOSFET.

7.3.15.1 High-Side MOSFET Overcurrent Protection

High-side MOSFET overcurrent protection is achieved by an internal current comparator that monitors the current in the high-side MOSFET on a cycle-by-cycle basis. If this current exceeds the current limit threshold, the highside MOSFET is turned off for the remainder of that switching cycle.

During normal operation, the device implements current mode control which uses the COMP pin voltage to control the turn off of the high-side MOSFET and the turn on of the low-side MOSFET, on a cycle-by-cycle basis. Each cycle, the switch current and the current reference generated by the COMP pin voltage are compared. When the peak switch current intersects the current reference, the high-side switch is turned off.

7.3.15.2 Low-Side MOSFET Overcurrent Protection

While the low-side MOSFET is turned on, its conduction current is monitored by the internal circuitry. During normal operation, the low-side MOSFET sources current to the load. At the end of every clock cycle, the low-side MOSFET sourcing current is compared to the internally set low-side sourcing current limit. If the low-side sourcing current is exceeded, the high-side MOSFET is not turned on and the low-side MOSFET stays on for the next cycle. The high-side MOSFET is turned on again when the low-side current is below the low-side sourcing current limit at the start of a cycle.

The low-side MOSFET may also sink current from the load. If the low-side sinking current limit is exceeded, the low-side MOSFET is turned off immediately for the rest of that clock cycle. In this scenario both MOSFETs are off until the start of the next cycle.

Furthermore, if an output overload condition (as measured by the COMP pin voltage) has lasted for more than the hiccup wait time which is programmed for 512 switching cycles, the device shuts down and restarts after the hiccup time, which is set for 16384 cycles. The hiccup mode helps to reduce the device power dissipation under severe overcurrent conditions.

7.3.16 Thermal Shutdown

The internal thermal shutdown circuitry forces the device to stop switching if the junction temperature exceeds 175°C typically. The device reinitiates the power-up sequence when the junction temperature drops below 165°C typically.

7.3.17 Small Signal Model for Loop Response

[Figure](#page-17-0) 28 shows an equivalent model for the device's control loop, which can be modeled in a circuit simulation program to check frequency response and transient responses. The error amplifier is a transconductance amplifier with a gm of 1300 μA/V. The error amplifier can be modeled using an ideal voltage controlled current source. The resistor Roea (2.38 MΩ) and capacitor Coea (20.7 pF) model the open-loop gain and frequency response of the error amplifier. The 1-mV ac voltage source between the nodes a and b effectively breaks the control loop for the frequency response measurements. Plotting a/c and c/b shows the small signal responses of the power stage and frequency compensation respectively. Plotting a/b shows the small signal response of the overall loop. The dynamic loop response can be checked by replacing the R_1 with a current source with the appropriate load step amplitude and step rate in a time domain analysis.

Figure 28. Small Signal Model for Loop Response

7.3.18 Simple Small Signal Model for Peak Current Mode Control

[Figure](#page-18-0) 29 is a simple small signal model that can be used to understand how to design the frequency compensation. The device's power stage can be approximated to a voltage controlled current source (duty cycle modulator) supplying current to the output capacitor and load resistor. The control to output transfer function is shown in [Equation](#page-18-1) 9 and consists of a dc gain, one dominant pole, and one equivalent series resistance (ESR) zero. The quotient of the change in switch current and the change in COMP pin voltage (node c in [Figure](#page-17-0) 28) is the power stage transconductance (gm_{ps}), which is 12 A/V for the device. The DC gain of the power stage is the product of gm_{ps} and the load resistance (R_L), as shown in [Equation](#page-18-2) 10 with resistive loads. As the load current increases, the DC gain decreases. This variation with load may seem problematic at first glance, but fortunately the dominant pole moves with load current (see [Equation](#page-18-3) 11). The combined effect is highlighted by the dashed line in [Figure](#page-18-4) 30. As the load current decreases, the gain increases and the pole frequency lowers, keeping the 0-dB crossover frequency the same for the varying load conditions, which makes it easier to design the frequency compensation.

Figure 29. Simplified Small Signal Model for Peak Current Mode Control

Figure 30. Simplified Frequency Response for Peak Current Mode Control

$$
\frac{\text{VOUT}}{\text{VC}} = \text{Adv} \times \frac{\left(1 + \frac{\text{s}}{2\pi \times f\text{z}}\right)}{\left(1 + \frac{\text{s}}{2\pi \times f\text{p}}\right)}
$$

 $\text{Adc} = \text{am}_{\text{res}} \times \text{R}_{0}$ $2\pi \times fp$ π

$$
f \mathbf{p} = \frac{1}{C_0 \times R_L \times 2\pi}
$$
(10)

$$
fz = \frac{1}{C_0 \times R_{ESR} \times 2\pi}
$$

where

- gm_{ea} is the GM amplifier gain (1300 μ A/V).
- gm_{ps} is the power stage gain (12 A/V).
- R_{L} is the load resistance.
- C_O is the output capacitance.
- R_{ESR} is the equivalent series resistance of the output capacitor. (12)

(9)

7.3.19 Small Signal Model for Frequency Compensation

The device uses a transconductance amplifier for the error amplifier and readily supports two of the commonly used Type II compensation circuits and a Type III frequency compensation circuit, as shown in [Figure](#page-19-0) 31. In Type 2A, one additional high-frequency pole, C6, is added to attenuate high frequency noise. In Type III, one additional capacitor, C11, is added to provide a phase boost at the crossover frequency. See *Designing Type III Compensation for Current Mode Step-Down Converters* [\(SLVA352\)](http://www.ti.com/cn/lit/pdf/SLVA352) for a complete explanation of Type III compensation.

The design guidelines below are provided for advanced users who prefer to compensate using the general method. The following equations only apply to designs which have ESR zero above the bandwidth of the control loop. This is usually true with ceramic output capacitors.

Figure 31. Types of Frequency Compensation

The general design guidelines for device loop compensation are as follows:

VOUT

- 1. Determine the crossover frequency, f_c . A good starting point is 1/10 of the switching frequency, f sw.
- 2. R4 can be determined by:

$$
R4 = \frac{2\pi \times fc \times VOUT \times Co}{gm_{ea} \times Vref \times gm_{ps}}
$$

where

20

- gm_{ea} is the GM amplifier gain (1300 μA/V).
- gm_{DS} is the power stage gain (12 A/V).
- Vref is the reference voltage (0.8 V). (13)

3. Place a compensation zero at the dominant pole:

C4 can be determined by:\n
$$
\sum_{n=1}^{\infty} \binom{n}{n} \binom{n}{n}
$$

$$
C4 = \frac{R_L \times Co}{R4} \tag{14}
$$

o ^ '`L $\left(f_{\mathsf{p}} = \frac{1}{C_{\mathsf{O}} \times R_{\mathsf{I}} \times 2\pi}\right)$ $\begin{pmatrix} 0 & x & R_L \end{pmatrix}$ $\begin{pmatrix} 0 & x & z \end{pmatrix}$

C6 is optional. It can be used to cancel the zero from the ESR of the output capacitor, C_0 .

$$
C6 = \frac{R_{ESR} \times Co}{R4} \tag{15}
$$

5. Type III compensation can be implemented with the addition of one capacitor, C11. This allows for slightly higher loop bandwidths and higher phase margins. If used, C11 is calculated from [Equation](#page-19-1) 16.

$$
C11 = \frac{1}{(2 \cdot \pi \cdot R8 \cdot fc)}\tag{16}
$$

7.4 Device Functional Modes

7.4.1 Adjustable Switching Frequency and Synchronization (RT/CLK)

The RT/CLK pin can be used to set the switching frequency of the device in two modes.

In RT mode, a resistor (RT resistor) is connected between the RT/CLK pin and GND. The switching frequency of the device is adjustable from 200 to 1200 kHz by using a maximum of 240 kΩ and minimum of 40.2 kΩ respectively. In CLK mode, an external clock is connected directly to the RT/CLK pin. The device is synchronized to the external clock frequency with a PLL.

The CLK mode overrides the RT mode. The device is able to detect the proper mode automatically and switch from the RT mode to CLK mode.

7.4.2 Adjustable Switching Frequency (RT Mode)

To determine the RT resistance for a given switching frequency, use [Equation](#page-20-2) 17 or the curve in [Figure](#page-20-3) 32. To reduce the solution size, one would set the switching frequency as high as possible, but consider the tradeoffs of the supply efficiency and minimum controllable on-time.

Rrt(kΩ) = 60281-Fsw (kHz)^{-1.033} (17)
\n
$$
\frac{250}{200}
$$
\n
$$
\frac{1}{250}
$$
\n
$$
\frac{150}{200}
$$
\n
$$
\frac{150}{200}
$$
\n
$$
\frac{50}{200}
$$
\n
$$
\frac{1}{200}
$$
\n
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\frac{50}{200}
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\n
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\frac{1}{200}
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\n
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\frac{50}{200}
$$
\n
$$
\frac{1}{200}
$$
\n
$$
\frac{500}{200}
$$
\n
$$
\frac{600}{200}
$$
\n
$$
\frac{700}{200}
$$
\n
$$
\frac{800}{200}
$$
\n
$$
\frac{700}{200}
$$
\n
$$
\frac{800}{200}
$$
\n
$$
\frac{900}{200}
$$
\n
$$
\frac{1}{200}
$$
\n
$$
\frac{1
$$

Figure 32. RT Set Resistor vs Switching Frequency

7.4.3 Synchronization (CLK Mode)

An internal PLL has been implemented to allow synchronization between 200 kHz and 1.2 MHz, and to easily switch from RT mode to CLK mode.

To implement the synchronization feature, connect a square wave clock signal to the RT/CLK pin with a duty cycle between 20% to 80%. The clock signal amplitude must transition lower than 0.8 V and higher than 2.0 V. The start of the switching cycle is synchronized to the falling edge of RT/CLK pin.

Device Functional Modes (continued)

In applications where both RT mode and CLK mode are needed, the device can be configured as shown in [Figure](#page-21-1) 33. Before the external clock is present, the device works in RT mode and the switching frequency is set by RT resistor. When the external clock is present, the CLK mode overrides the RT mode. The first time the RT/CLK pin is pulled above the RT/CLK high threshold (2.0 V), the device switches from the RT mode to the CLK mode and the RT/CLK pin becomes high impedance as the PLL starts to lock onto the frequency of the external clock. TI does not recommend to switch from the CLK mode back to the RT mode, because the internal switching frequency drops to 100 kHz first before returning to the switching frequency set by RT resistor.

Figure 33. Works With Both RT Mode and CLK Mode

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TPS54320 device is an integrated synchronous step-down DC-DC converter. The integrated MOSFETs allow for high-efficiency power supply designs with continuous output currents up to 3 A.

8.2 Typical Application

The application schematic of [Figure](#page-22-3) 34 was developed to meet the requirements. This circuit is available as the TPS54320EVM-513 evaluation module. The design procedure is provided in the following sections.

Figure 34. Typical Application Circuit

8.2.1 Design Requirements

This example details the design of a high-frequency switching regulator using ceramic output capacitors. A few parameters must be known to start the design process. These parameters are typically determined at the system level. For this example, start with the following known parameters:

Table 1. Design Parameters

8.2.2 Detailed Design Procedure

8.2.2.1 Custom Design With WEBENCH® Tools

[Click](https://webench.ti.com/wb5/WBTablet/PartDesigner/quickview.jsp?base_pn=TPS54320&origin=ODS&litsection=application) here to create a custom design using the TPS54320 device with the WEBENCH® Power Designer.

- 1. Start by entering the input voltage (V_{N}) , output voltage (V_{OUT}) , and output current (I_{OUT}) requirements.
- 2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
- 3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at [www.ti.com/WEBENCH.](http://www.ti.com/lsds/ti/analog/webench/overview.page?DCMP=sva_web_webdesigncntr_en&HQS=sva-web-webdesigncntr-vanity-lp-en)

8.2.2.2 Operating Frequency

The first step is to decide on a switching frequency for the regulator. There is a trade off between higher and lower switching frequencies. Higher switching frequencies may produce a smaller solution size using lower valued inductors and smaller output capacitors compared to a power supply that switches at a lower frequency. However, the higher switching frequency causes additional switching losses, which negatively impact the converter's efficiency and thermal performance. In this design, a moderate switching frequency of 480 kHz is selected to achieve both a small solution size and a high-efficiency operation. This frequency is set using the resistor at the RT/CLK pin (R3). Using [Equation](#page-20-2) 17, the resistance required for a switching frequency of 480 kHz is 102 kΩ. A 100-kΩ resistor is used for this design.

8.2.2.3 Output Inductor Selection

To calculate the value of the output inductor, [Equation](#page-23-0) 18 is used. KIND is a coefficient that represents the amount of inductor ripple current relative to the maximum output current. The inductor ripple current is filtered by the output capacitor. Therefore, choosing a high inductor ripple current impacts the selection of the output capacitor because the output capacitor must have a ripple current rating equal to or greater than the inductor ripple current. Usually, the inductor ripple value is at the discretion of the designer; however, KIND is normally from 0.2 to 0.4 for the majority of applications.

$$
L1 = \frac{Vinmax - Vout}{Iout \cdot KIND} \cdot \frac{Vout}{Vinmax \cdot fsw}
$$
 (18)

For this design example using KIND = 0.3, the inductor value is calculated to be 6.2 μ H. The nearest standard value of 6.8 µH was chosen. For the output filter inductor, it is important that the RMS current and saturation current ratings not be exceeded. The inductor ripple current, RMS current, and peak inductor current can be found from [Equation](#page-23-1) 19, [Equation](#page-23-2) 20, and [Equation](#page-23-3) 21.

$$
I = \frac{Vinnax - Vout}{L1} \cdot \frac{Vout}{Vinnax \cdot fsw}
$$
\n
$$
I Lrms = \sqrt{lout^{2} + \frac{1}{12} \cdot \left(\frac{Vout \cdot (Vinnax - Vout)}{Vinnax \cdot L1 \cdot fsw}\right)^{2}}
$$
\n
$$
I L peak = lout + \frac{I ripple}{2}
$$
\n(21)

For this design, the inductor ripple current is 815 mA, the RMS inductor current is 3.01 A, and the peak inductor current is 3.41 A. A 6.8-µH TDK VLP8040 series inductor was chosen for its small size and low DCR. It has a saturation current rating of 3.6 A and a RMS current rating of 4 A.

The current flowing through the inductor is the inductor ripple current plus the output current. During power up, faults or transient load conditions, the inductor current can increase above the calculated peak inductor current level calculated above. In transient conditions, the inductor current can increase up to the switch current limit of the device. For this reason, the most conservative approach is to specify an inductor with a saturation current rating equal to or greater than the switch current limit rather than the peak inductor current.

8.2.2.4 Output Capacitor Selection

The three primary considerations for selecting the value of the output capacitor are:

- Minimum capacitance to meet the load transient requirement
- Minimum capacitance to meet the output voltage ripple requirement
- Maximum ESR to meet the output voltage ripple requirement

The output capacitor must be selected based on the most stringent of these three criteria.

The first criterion is the desired response to a large change in the load current. The output capacitor needs to supply the load with current when the regulator cannot. This situation would occur if there are desired hold-up times for the regulator where the output capacitor must hold the output voltage above a certain level for a specified amount of time after the input power is removed. The regulator is also temporarily not able to supply sufficient output current if there is a large, fast increase in the current needs of the load such as transitioning from no load to a full load. The regulator usually needs two or more clock cycles for the control loop to see the change in load current and output voltage and adjust the duty cycle to react to the change. The output capacitor must be sized to supply the extra current to the load until the control loop responds to the load change. The output capacitance must be large enough to supply the difference in current for 2 clock cycles while only allowing a tolerable amount of droop in the output voltage. [Equation](#page-24-0) 22 shows the minimum output capacitance necessary to accomplish this.

$$
Co > \frac{2 \cdot \Delta lout}{fsw \cdot \Delta Vout}
$$

where

- ΔIout is the change in output current.
- f sw is the regulator's switching frequency.
- ΔVout is the allowable change in the output voltage. (22)

For this example, the transient load response is specified as a 4% change in Vout for a load step of 0.75 A. Using these numbers (ΔI_{OUT} = 0.75 A and Δ Vout = 0.04 x 3.3 = 0.132 V) gives a minimum capacitance of 23.7 μF. This value does not take the ESR of the output capacitor into account in the output voltage change. For ceramic capacitors, the ESR is usually small enough to ignore in this calculation.

[Equation](#page-24-1) 23 calculates the minimum output capacitance needed to meet the output voltage ripple specification. Where fsw is the switching frequency, Voripple is the maximum allowable output voltage ripple, and Iripple is the inductor ripple current. In this case, the maximum output voltage ripple is 33 mV. Under this requirement, [Equation](#page-24-1) 23 yields 6.4 µF.

$$
\text{Co} > \frac{1}{8 \cdot f \text{sw}} \cdot \frac{1}{\text{Voripple}}
$$

[Equation](#page-24-2) 24 calculates the maximum ESR an output capacitor can have to meet the output voltage ripple specification. [Equation](#page-24-2) 24 indicates the ESR should be less than 40 m Ω . In this case, the ESR of the ceramic capacitor is much smaller than 40 m Ω .

$$
Resr < \frac{\text{Voripple}}{\text{Iripple}}\tag{24}
$$

The capacitance of ceramic capacitors is highly dependent on the DC output voltage. [Equation](#page-24-3) 25 is used to select output capacitors based on their voltage rating. For 6.3-V ceramic capacitors, the minimum capacitance that meets the load step specification is 49.7 µF. For this example, one 47-μF, 6.3-V, X5R ceramic capacitor with 4 m Ω of ESR is used.

$$
C = \frac{(Ceff \times Variing)}{(Vrating - Vout)}
$$

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25 (25)

(23)

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Capacitors generally have limits to the amount of ripple current they can handle without failing or producing excess heat. The designer must specify an output capacitor that can support the inductor ripple current. Some capacitor data sheets specify the root mean square (RMS) value of the maximum ripple current. [Equation](#page-25-0) 26 can be used to calculate the RMS ripple current the output capacitor needs to support. For this application, [Equation](#page-25-0) 26 yields 235 mA.

$$
Icorns = \frac{Vout \cdot (Vinnax - Vout)}{\sqrt{12} \cdot Vinnax \cdot L1 \cdot fsw}
$$

8.2.2.5 Input Capacitor Selection

 Γ

The TPS54320 requires a high-quality ceramic, type X5R or X7R, input decoupling capacitor of 4.7 µF on each input voltage rail. In some applications, additional bulk capacitance may also be required for the PVIN input. The voltage rating of the input capacitor must be greater than the maximum input voltage. The capacitor must also have a ripple current rating greater than the maximum input current ripple of the TPS54320. The input ripple current for this design, using [Equation](#page-25-1) 27, is 1.48 A.

lcirms = lout
$$
\sqrt{\frac{Vout}{Vinmin} \cdot \frac{(Vinmin - Vout)}{Vinmin}}
$$

\nThe value of a ceramic capacitor varies significantly over both temperature and the amount of DC bias applied to

the capacitor. The capacitance variations due to temperature can be minimized by selecting a dielectric material that is stable over temperature. X5R and X7R ceramic dielectrics are usually selected for power regulator capacitors because of the high capacitance to volume ratio and stability over temperature. The capacitance value of a capacitor decreases as the DC bias across it increases. For this example design, a ceramic capacitor with at least a 25-V voltage rating is required to support the maximum input voltage. For this example, two 4.7-µF 25-V capacitors were used in parallel as the VIN and PVIN inputs are tied together, so the TPS54320 may operate from a single supply. The input capacitance value determines the input ripple voltage of the regulator. The input voltage ripple can be calculated using [Equation](#page-25-2) 28. Using the design example values, Ioutmax = 3 A, C_{IN} = 9.4 μ F, fsw = 480 kHz, [Equation](#page-25-2) 28 yields an input voltage ripple of 166 mV.

$$
\Delta \text{Vin} = \frac{\text{Ioutmax} \cdot 0.25}{\text{Cin} \cdot f \text{sw}}
$$

8.2.2.6 Slow-Start Capacitor Selection

The slow-start capacitor determines the minimum amount of time it takes for the output voltage to reach its nominal programmed value during power up. This is useful if a load requires a controlled voltage slew rate. This is also used if the output capacitance is large and requires a large amount of current to charge the capacitor to the output voltage level. The large currents necessary to charge the capacitor may either make the TPS54320 reach the current limit or the excessive current draw from the input power supply may cause the input voltage rail to sag. Limiting the output voltage slew rate solves both of these problems. The soft-start capacitor value can be calculated using [Equation](#page-25-3) 29. The example circuit has the soft-start time set to an arbitrary value of 3.5 ms, which requires a 10-nF capacitor. In the TPS54320, Iss is 2.3 µA and Vref is 0.8 V.

$$
C5(nF) = \frac{Tss(ms) \times Iss(\mu A)}{Vref(V)}
$$

8.2.2.7 Bootstrap Capacitor Selection

A 0.1-µF ceramic capacitor must be connected between the BOOT to PH pin for proper operation. TI recommends to use a ceramic capacitor with X5R or better grade dielectric. The capacitor should have 10 V or higher voltage rating.

26

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FXAS

(26)

(28)

(29)

8.2.2.8 UVLO Set Point

The UVLO can be adjusted using the external voltage divider network of R1 and R2. R1 is connected between VIN and the EN pin of the TPS54320 and R2 is connected between EN and GND. The UVLO has two thresholds, one for power-up when the input voltage is rising and one for power-down or brownouts when the input voltage is falling. For the example design, the supply should turn on and start switching once the input voltage increases above 6.806 V (UVLO start or enable). After the regulator starts switching, it should continue to do so until the input voltage falls below 4.824 V (UVLO stop or disable). [Equation](#page-12-4) 2 and [Equation](#page-12-0) 3 can be used to calculate the values for the upper and lower resistor values. For the stop voltages specified, the nearest standard resistor value for R1 is 511 kΩ and for R2 is 100 kΩ.

8.2.2.9 Output Voltage Feedback Resistor Selection

The resistor divider network, R8 and R9, is used to set the output voltage. For this example design, 10 kΩ was selected for R9. Using [Equation](#page-26-1) 30, R8 is calculated as 31.25 kΩ. The nearest standard 1% resistor is 31.6 kΩ.

$$
R8 = \frac{Vout - Vref}{Vref} R9
$$
 (30)

8.2.2.9.1 Minimum Output Voltage

Due to the internal design of the TPS54320, there is a minimum output voltage limit for any given input voltage. The output voltage can never be lower than the internal voltage reference of 0.8 V. Above 0.8 V, the output voltage may be limited by the minimum controllable on-time. The minimum output voltage in this case is given by [Equation](#page-26-2) 31.

 $V_{OUT}min =$ Ontimemin x Fsmax (V_{IN}max + I_{OUT}min (RDS2min – RDS1min)) – I_{OUT}min (R_L + RDS2min)

where

- V_{OUT} min = Minimum achievable output voltage
- Ontimemin = Minimum controllable on-time (135 ns maximum)
- Fsmax = Maximum switching frequency including tolerance
- V_{IN} max = Maximum input voltage
- I_{OUT} min = Minimum load current
- RDS1min = Minimum high-side MOSFET on resistance (57 mΩ typical)
- RDS2min = Minimum low-side MOSFET on resistance (50 mΩ typical)
- R_L = Series resistance of output inductor (31)

8.2.2.10 Compensation Component Selection

There are several industry techniques used to compensate DC/DC regulators. The method presented here is easy to calculate and yields high phase margins. For most conditions, the regulator has a phase margin between 60° and 90°. The method presented here ignores the effects of the slope compensation that is internal to the TPS54320. Since the slope compensation is ignored, the actual crossover frequency is usually lower than the crossover frequency used in the calculations. Use SwitcherPro software for a more accurate design.

Type III compensation is used to achieve a high-bandwidth, high-phase margin design. This design targets a crossover frequency (bandwidth) of 48 kHz (1/10 of the switching frequency). Using [Equation](#page-26-3) 32 and [Equation](#page-26-4) 33, the power stage pole and zero are calculated at 6.46 and 1778 kHz, respectively. For the output capacitance, C_0 , use a derated value of 22.4 μ F.

$$
f\text{pmod} = \frac{\text{lout}}{2 \cdot \pi \cdot \text{Vout} \cdot \text{Co}}
$$
\n
$$
f\text{zmod} = \frac{1}{2 \cdot \pi \cdot \text{RESR} \cdot \text{Co}}
$$
\n(32)

Now the compensation components can be calculated. First, calculate the value for R4 which sets the gain of the compensated network at the crossover frequency. Use [Equation](#page-26-5) 34 to determine the value of R4.

$$
R4 = \frac{2\pi \cdot fc \cdot Vout \cdot Co}{gm_{ea} \cdot Vref \cdot gm_{ps}}
$$
 (34)

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Next calculate the value of C4. Together with R4, C4 places a compensation zero at the modulator pole frequency. Use [Equation](#page-27-0) 35 to determine the value of C4.

$$
C4 = \frac{Vout \cdot Co}{Iout \cdot R4}
$$
 (35)

Using [Equation](#page-27-0) 34 and Equation 35, the standard values for R4 and C4 are 1.78 kΩ and 0.015 µF. The next higher standard value for C4 is selected to give a compensation zero that is slightly lower in frequency than the power stage pole.

To provide a zero around the crossover frequency to boost the phase at crossover, a capacitor (C11) is added parallel to R8. The value of this capacitor is given by [Equation](#page-27-1) 36. The nearest standard value for C11 is 100 pF.

$$
C11 = \frac{1}{2 \cdot \pi \cdot R8 \cdot fc}
$$
\n(36)

Use of the feed-forward capacitor, C11, creates a low-AC impedance path from the output voltage to the VSENSE input of the IC that can couple noise at the switching frequency into the control loop. TI does not recommend use of a feed-forward capacitor for high-output voltage ripple designs (greater than 15-mV peak to peak at the VSENSE input) operating at duty cycles of less than 30%. When using the feed-forward capacitor, C11, always limit the closed loop bandwidth to no more than 1/10 of the switching frequency, ƒsw.

An additional high-frequency pole can be used if necessary by adding a capacitor in parallel with the series combination of R4 and C4. [Equation](#page-27-2) 37 gives the pole frequency. This pole is set at roughly half of the switching frequency (of 480 kHz) by use of a 330-pF capacitor for C6. This helps attenuate any high-frequency signals that might couple into the control loop.

$$
f \mathbf{p} = \frac{1}{2 \cdot \pi \cdot \mathbf{R} \cdot \mathbf{C} \mathbf{6}} \tag{37}
$$

8.2.3 Application Curves

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9 Power Supply Recommendations

The TPS54320 is designed to operate from an input voltage supply range between 4.5 and 17 V. This supply voltage must be well regulated. Power supplies must be well bypassed for proper electrical performance. This includes a minimum of one 4.7 μF (after derating) ceramic capacitor, type X5R or better from PVIN to GND, and from VIN to GND. Additional local ceramic bypass capacitance may be required in systems with small input ripple specifications, in addition to bulk capacitance if the TPS54320 device is located more than a few inches away from its input power supply. In systems with an auxiliary power rail available, the power stage input, PVIN, and the analog power input, VIN, may operate from separate input supplies. See [Figure](#page-33-1) 56 (layout recommendation) for recommended bypass capacitor placement.

10 Layout

10.1 Layout Guidelines

Layout is a critical portion of good power supply design. See [Figure](#page-33-1) 56 for a PCB layout example. The top layer contains the main power traces for VIN, VOUT, and the PH node. Also on the top layer are connections for the remaining pins of the TPS54320 and a large top-side area filled with ground. The top layer ground area should be connected to the internal ground layer or layers using vias at the input bypass capacitor, the output filter capacitor, and directly under the TPS54320 device to provide a thermal path from the exposed thermal pad land to ground. The GND pin should be tied directly to the exposed thermal pad under the IC.

For operation at full-rated load, the top-side ground area together with the internal ground plane must provide adequate heat dissipating area. Several signals paths conduct fast-changing currents or voltages that can interact with stray inductance or parasitic capacitance to generate noise or degrade the power supplies performance. To help eliminate these problems, the PVIN pin should be bypassed to ground with a low-ESR ceramic bypass capacitor with X5R or X7R dielectric. Take care to minimize the loop area formed by the bypass capacitor connections, the PVIN pins, and the ground connections. The VIN pin must also be bypassed to ground using a low-ESR ceramic capacitor with X5R or X7R dielectric. Make sure to connect this capacitor to the quiet analog ground trace rather than the power ground trace of the PVIN bypass capacitor.

Because the PH connection is the switching node, the output inductor should be located close to the PH pins, and the area of the PCB conductor minimized to prevent excessive capacitive coupling. The output filter capacitor ground should use the same power ground trace as the PVIN input bypass capacitor. Try to minimize this conductor length while maintaining adequate width. The small signal components should be grounded to the analog ground path as shown. The RT/CLK pin is sensitive to noise so the RT resistor should be located as close as possible to the IC and routed with minimal lengths of trace. The additional external components can be placed approximately as shown. It may be possible to obtain acceptable performance with alternate PCB layouts. However, this layout has been shown to produce good results and is meant as a guideline.

The estimated PCB area for the components used in the design of [Figure](#page-22-3) 34 is 0.35 in² (227 mm²). This area does not include test points or connectors.

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10.2 Layout Example

11 器件和文档支持

11.1 器件支持

11.1.1 使用 **WEBENCH®** 工具创建定制设计

[单击此处](https://webench.ti.com/wb5/WBTablet/PartDesigner/quickview.jsp?base_pn=TPS54320&origin=ODS&litsection=device_support),使用 TPS54320 器件并借助 WEBENCH® 电源设计器创建定制设计方案。

- 1. 首先键入输入电压 (V_{IN})、输出电压 (V_{OUT}) 和输出电流 (I_{OUT}) 要求。
- 2. 使用优化器拨盘优化关键参数设计,如效率、封装和成本。
- 3. 将生成的设计与德州仪器 (TI) 的其他解决方案进行比较。

WEBENCH 电源设计器可提供定制原理图以及罗列实时价格和组件供货情况的物料清单。

在多数情况下,可执行以下操作:

- 运行电气仿真,观察重要波形以及电路性能
- 运行热性能仿真,了解电路板热性能
- 将定制原理图和布局方案导出至常用 CAD 格式
- 打印设计方案的 PDF 报告并与同事共享

有关 WEBENCH 工具的详细信息,请访问 [www.ti.com.cn/WEBENCH](http://www.ti.com.cn/zh-cn/design-tools/overview.html?DCMP=sva_web_webdesigncntr_cn&HQS=sva-web-webdesigncntr-vanity-lp-cn)。

11.2 文档支持

有关第 II 类和第 III 类频率补偿电路的更多信息,请参阅《设计用于电流模式降压转换器的第 *III* 类补偿》 [\(SLVA352\)](http://www.ti.com/cn/lit/pdf/SLVA352) 和《设计计算器》[\(SLVC219\)](http://www.ti.com.cn/tool/cn/tps54620design-calc)。

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11.4 静电放电警告

ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序 , 可 能会损坏集成电路。

 Λ % \blacktriangle ESD 的损坏小至导致微小的性能降级,大至整个器件故障。 精密的集成电路可能更容易受到损坏,这是因为非常细微的参数更改都可 能会导致器件与其发布的规格不相符。

11.5 术语表

[SLYZ022](http://www.ti.com/cn/lit/pdf/SLYZ022) — *TI* 术语表。

这份术语表列出并解释术语、缩写和定义。

12 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更,恕不另行通知,且 不会对此文档进行修订。如需获取此数据表的浏览器版本,请参阅左侧的导航栏。

www.ti.com 10-Dec-2020

PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures. "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

TEXAS

TAPE AND REEL INFORMATION

ISTRUMENTS

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

Pack Materials-Page 1

PACKAGE MATERIALS INFORMATION

www.ti.com 20-Apr-2023

*All dimensions are nominal

Pack Materials-Page 2

PACKAGE OUTLINE

RHL0014A VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

RHL0014A VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 6. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RHL0014A VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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